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FCD600N60Z N-Channel SuperFET[®] II MOSFET 600 V, 7.4 A, 600 mΩ

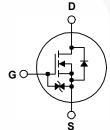
Features

- 650 V @ T₁ = 150°C
- Typ. R_{DS(on)} = 510 mΩ
- Ultra Low Gate Charge (Typ. Q_q = 20 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 74 pF)
- 100% Avalanche Tested
- · ESD Improved Capacity
- RoHS Compliant

Applications

- LCD / LED / PDP TV and Monitor Lighting
- · Solar Inverter
- AC-DC Power Supply





SuperFET[®] II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing

charge balance technology for outstanding low on-resistance

and lower gate charge performance. This technology is tailored

to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently,

SuperFET II MOSFET is very suitable for the switching power

applications such as PFC, server/telecom power, FPD TV

power, ATX power and industrial power applications.

Description

Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FCD600N60Z	Unit	
V _{DSS}	Drain to Source Voltage			600	V
V _{GSS}	Gate to Source Voltage	- DC		±20	V
	Gale to Source voltage	- AC	(f > 1 Hz)	±30	V
I _D	Drain Current	- Continuous (T _C = 25 ^o C)		7.4	A
	Dialit Current	- Continuous (T _C = 100 ^o C)		4.7	
DM	Drain Current	- Pulsed	(Note 1)	22.2	Α
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		135	mJ	
AR	Avalanche Current (Note 1)		1.5	Α	
AR	Repetitive Avalanche Energy (Note 1)		0.89	mJ	
dv/dt	MOSFET dv/dt			100	V/ns
	Peak Diode Recovery dv/dt (Note 3)			20	
P _D	Power Dissipation	$(T_{\rm C} = 25^{\rm o}{\rm C})$		89	W
		- Derate Above 25°C		0.71	W/ºC
Γ _J , T _{STG}	Operating and Storage Tempera	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temperature fo	r Soldering, 1/8" from Case for 5 Se	conds	300	°C

Thermal Characteristics

FCD600N60Z Rev. C3

Symbol	Parameter	FCD600N60Z	Unit	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	1.4	°C/W	
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient, Max.			

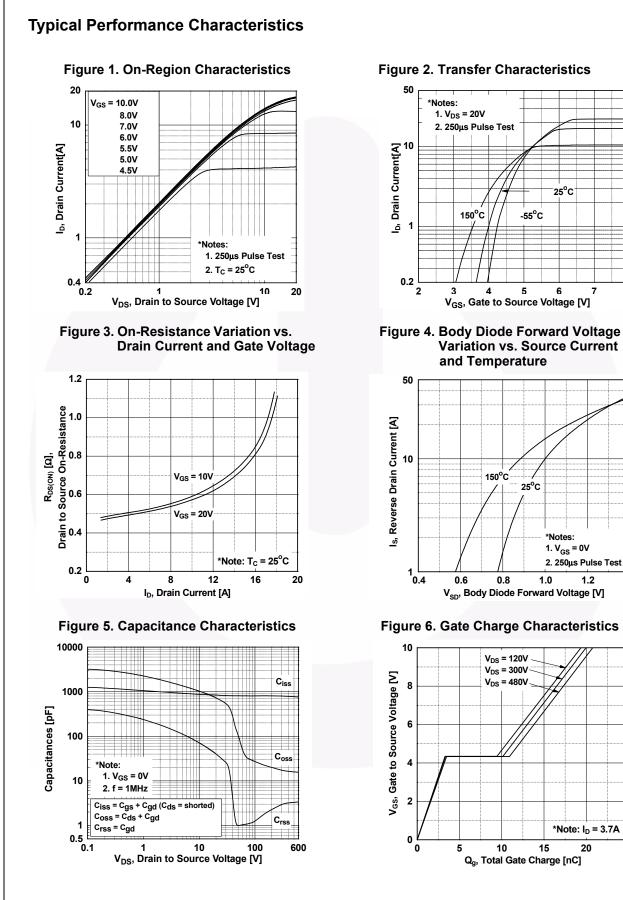
FCD600	Part NumberTop MaFCD600N60ZFCD6001		Package DPAK	Packing Method Tape and Reel	Reel Size 330 mm	-	e Width 6 mm		
Electrica	al Charac	teristics T _C =2	25°C unless o	otherwise noted.					
Symbol		Parameter		Test Conditio	ons	Min.	Тур.	Max.	Unit
	-	runneter					199.	mux.	onic
Off Chara	cteristics						1		
BV _{DSS} Drain to		to Source Breakdown Voltage		$V_{GS} = 0 V, I_D = 10 mA,$		600	-	-	v
	Breakdown	Voltage Temperatur	·0	$V_{GS} = 0 V, I_D = 10 mA, T_J = 150^{\circ}C$		650	-	-	
		eakdown Voltage Temperature efficient		I_D = 10 mA, Referenced to 25 ^o C		-	0.67	-	V/°C
Ŷ		ain to Source Avalanche Breakdown					700		V
BV _{DS}	Voltage			$V_{GS} = 0 V, I_D = 7.4 A$		-	700	-	v
I _{DSS}	Zero Gate \	/oltage Drain Currer	nt	V _{DS} = 480 V, V _{GS} = 0 V		-	-	5	μA
				$V_{DS} = 480 \text{ V}, \text{ T}_{C} = 125^{\circ}$		-	-	20	
I _{GSS}	Gate-Body	Leakage Current		$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$	/	-	-	±10	uA
On Chara	cteristics								
V _{GS(th)}	1	hold Voltage		V _{GS} = V _{DS} , I _D = 250 μA		2.5	-	3.5	V
R _{DS(on)}		to Source On Resis	stance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.7 \text{ A}$		-	0.51	0.6	Ω
9FS	Forward Transconductance			$V_{DS} = 20 \text{ V}, I_D = 3.7 \text{ A}$		-	6.7	-	S
				50 5					
-	Characteris	tics							
C _{iss}	Input Capac	citance		$V_{-2} = 25 V V_{-2} = 0 V$	_	-	840	1120	pF
C _{oss}	Output Cap	acitance		V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		-	630	840	pF
C _{rss}	Reverse Tra	Reverse Transfer Capacitance				-	30	45	pF
C _{oss}	Output Cap	acitance		V_{DS} = 380 V, V_{GS} = 0 V		-	16.5	-	pF
C _{oss(eff.)}		utput Capacitance		V_{DS} = 0 V to 480 V, V_{GS}	_S = 0 V	-	74	-	pF
Q _{g(tot)}		Charge at 10V		V _{DS} = 380 V, I _D = 3.7 A	٨,	-	20	26	nC
Q _{gs}		Irce Gate Charge		V _{GS} = 10 V		-	3.4	-	nC
Q _{gd}		Gate to Drain "Miller" Charge		(Note 4)		-	7.5	-	nC
ESR	Equivalent	Series Resistance		f = 1 MHz		-	2.89	-	Ω
Switching	Character	istics							
	Turn-On De					-	13	36	ns
t _{d(on)} t _r		Turn-On Rise Time		V_{DD} = 380 V, I _D = 3.7 A, V _{GS} = 10 V, R _G = 4.7 Ω		-	7	24	ns
t _{d(off)}	Turn-Off Delay Time					-	39	88	ns
-a(011) t _f	Turn-Off Fa				(Note 4)	-	9	28	ns
					(
Drain-Sou	rce Diode (Characteristics							
l _S	Maximum C	ontinuous Drain to S	Source Diode	de Forward Current		-	-	7.4	Α
I _{SM}	Maximum P	ulsed Drain to Sour	ce Diode For	orward Current		-	-	22.2	Α
		Irce Diode Forward	Voltage	V_{GS} = 0 V, I_{SD} = 3.7 A		-		1.2	V
V _{SD}	Reverse Re			$V_{GS} = 0 V, I_{SD} = 3.7 A,$ $dI_F/dt = 100 A/\mu s$		-	200	-	ns
V _{SD} t _{rr} Q _{rr}		covery Charge				-	2.3	-	μC

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1.2

1.4

8

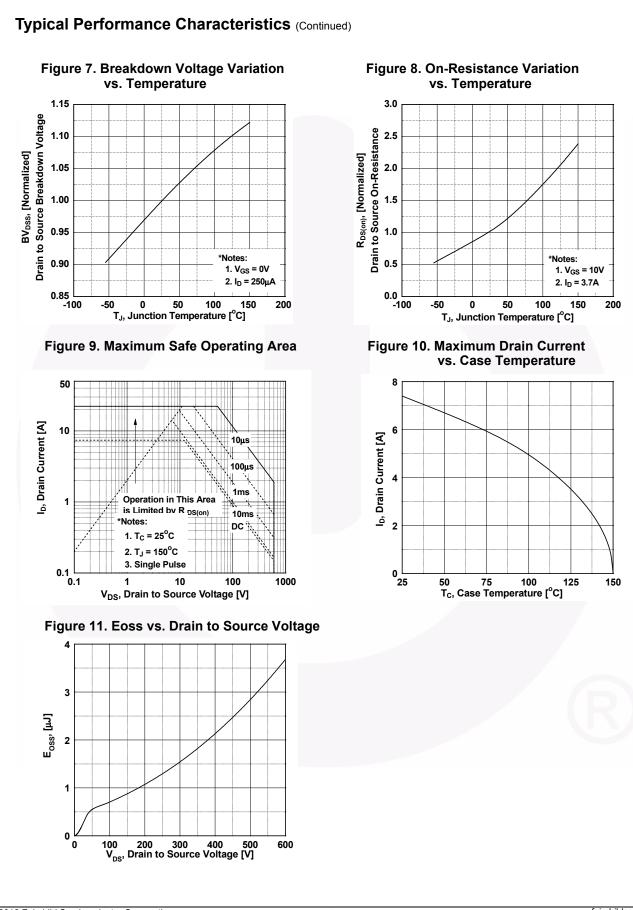


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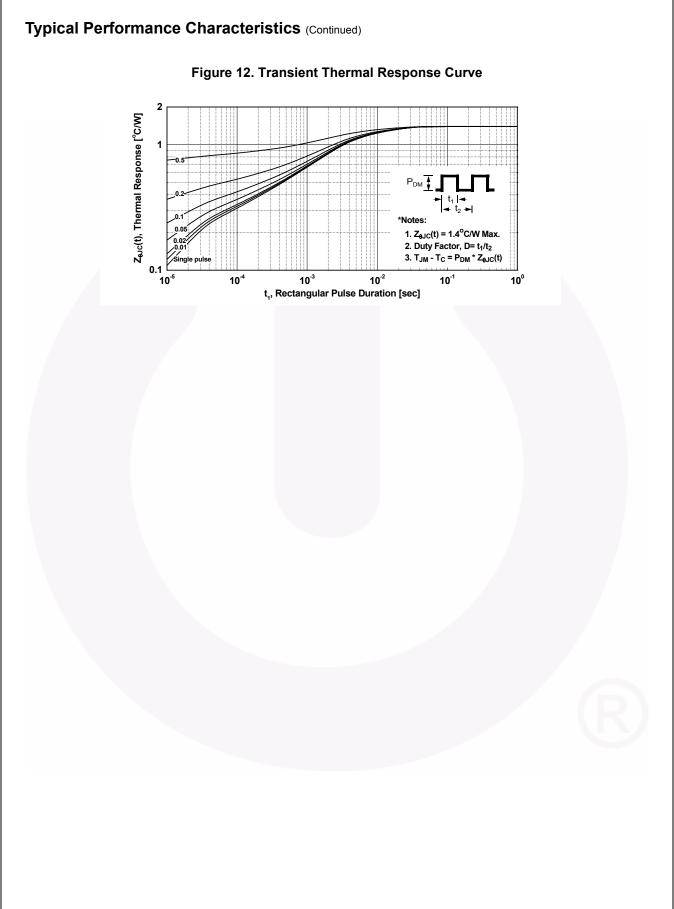
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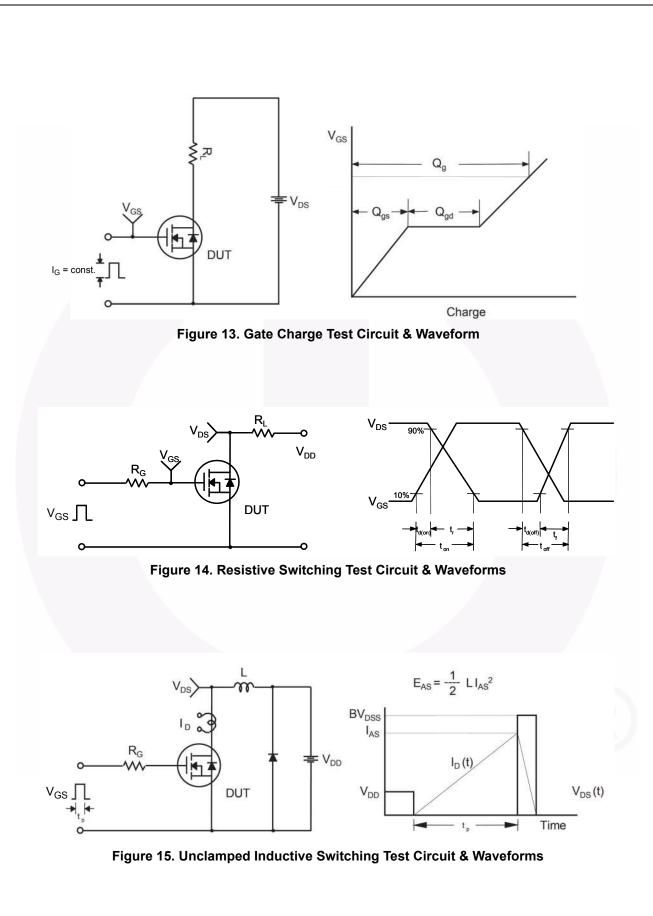
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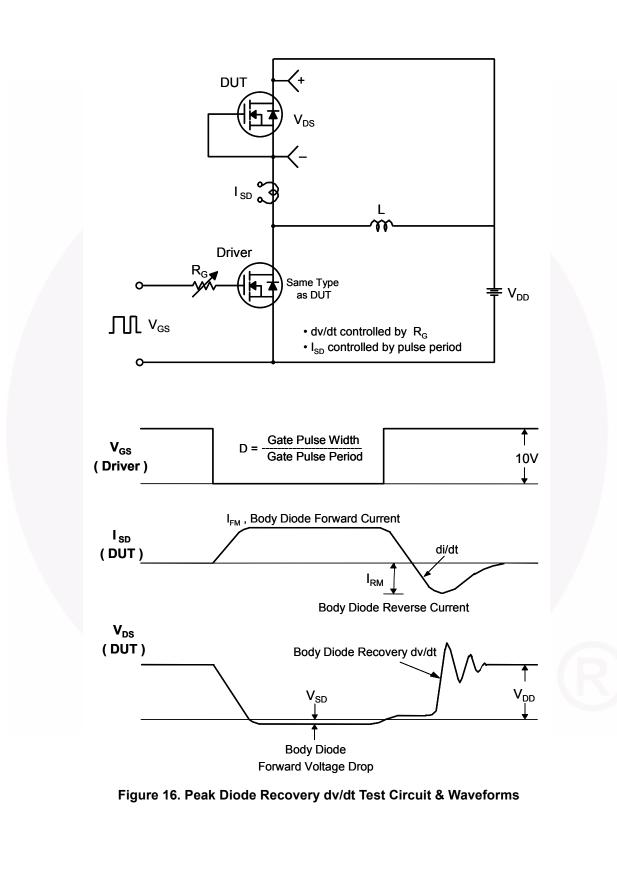


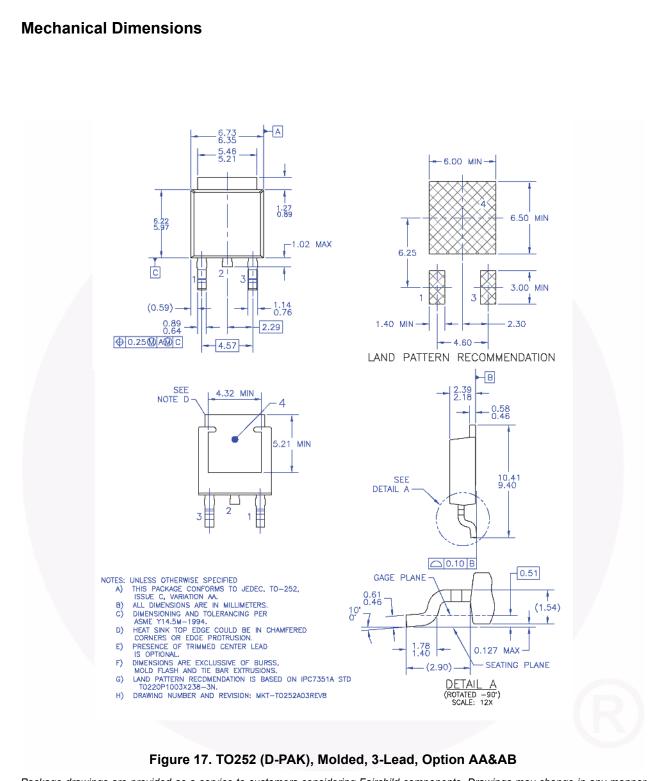


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